74F827 10-bit buffer/line driver; non-inverting; 3-state Rev. 04 — 29 January 2010

Product data sheet

1. General description

The 74F827 10-bit buffer, provides high performance bus interface buffering for wide data/address paths or buses carrying parity. The device has NOR output enables ($\overline{OE}0$, $\overline{OE}1$) for maximum control flexibility.

2. Features

- High impedance NPN base inputs for reduced loading (20 µA input current in HIGH and LOW states)
- I_{IL} = 20 μ A compared to 600 μ A in FAST family specification
- Ideal for high speed, light bus loading with increased fan-in
- Controlled rise and fall times to minimize ground bounce
- Glitch-free power-up in 3-state
- Flow-through pinout architecture for microprocessor oriented applications
- Output sink capability, I_{OL} = 64 mA

3. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
N74F827D	0 °C to 70 °C	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1
N74F827DB	0 °C to 70 °C	SSOP24	plastic shrink small outline package; 24 leads; body width 5.3 mm	SOT340-1



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4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2.	Pin description			
Symbol	Pin	Description	Unit load HIGH/LOW	Load value ^[1] HIGH/LOW
OE0	1	output enable input (active LOW)	1.0/0.033	20 μΑ/20 μΑ
A0 to A9	2, 3, 4, 5, 6, 7, 8, 9, 10, 11	data input	1.0/0.033	20 μΑ/20 μΑ
GND	12	ground (0 V)	-	-
OE1	13	output enable input (active LOW)	1.0/0.033	20 μΑ/20 μΑ
Y0 to Y9	23, 22, 21, 20, 19, 18, 17, 16, 15, 14	data output	1200/106.7	24 mA/64 mA
V _{CC}	24	supply voltage	-	-

[1] One FAST Unit Load (UL) is defined as 20 μ A in HIGH state, 0.6 μ A in LOW state.

6. Functional description

6.1 Function table

Table 3.Function selection^[1]

Input		Output	Status
OEn	An	Yn	
L	L	L	transparent
L	Н	Н	
Н	Х	Z	disabled

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high-impedance OFF-state.

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	М	lin	Max	Unit
V _{CC}	supply voltage		-(0.5	+7.0	V
VI	input voltage		<u>[1]</u> _(0.5	+7.0	V
Vo	output voltage	output in HIGH-state	<u>[1]</u> _(0.5	+7.0	V
I _{IK}	input clamping current	V _I < 0 V	-3	30	+5	mA
lo	output current	output in LOW-state	-		128	mA
T _{amb}	ambient temperature	in free-air	<u>[2]</u> 0		70	°C
T _{stg}	storage temperature		-6	65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		4.5	5.0	5.5	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.8	V
I _{IK}	input clamping current		-18	-	-	mA
I _{OH}	HIGH-level output current		-24	-	-	mA
I _{OL}	LOW-level output current		-	-	64	mA

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9. Static characteristics

Table 6.	Static characteristics								
Symbol	Parameter	Conditions			25 °C		0 °C to	70 °C	Unit
				Min	Typ[1]	Max	Min	Max	
V _{IK}	input clamping voltage	V_{CC} = 4.5 V; I _{IK} = -18 mA		-1.2	-0.73	-	-1.2	-	V
V _{OH}	HIGH-level output voltage	V_{CC} = 4.5 V; V_{IL} = 0.8 V; V_{IH} = 2.0 V							
		I _{OH} = -15 mA							
		$V_{CC} = \pm 10$ %		-	-	-	2.4	-	V
		$V_{CC} = \pm 5 \%$		-	3.3	-	2.4	-	V
		$I_{OH} = -24 \text{ mA}$							
		$V_{CC} = \pm 10 \%$		-	-	-	2.0	-	V
		$V_{CC} = \pm 5 \%$		-	-	-	2.0	-	V
V _{OL}	LOW-level output voltage	V_{CC} = 4.5 V; V_{IL} = 0.8 V; V_{IH} = 2.0 V							
		I _{OL} = 64 mA							
		$V_{CC} = \pm 10$ %		-	-	-	-	0.55	V
		$V_{CC} = \pm 5 \%$		-	0.42	-	-	0.55	V
l _l	input leakage current	$V_{CC} = 0 V; V_I = 7.0 V$		-	-	-	-	100	μΑ
I _{IH}	HIGH-level input current	$V_{CC} = 5.5 \text{ V}; \text{ V}_{I} = 2.7 \text{ V}$		-	-	-	-	20	μΑ
I _{IL}	LOW-level input current	$V_{CC} = 5.5 \text{ V}; \text{ V}_{I} = 0.5 \text{ V}$		-	-	-	-	-20	μΑ
I _{OZ}	OFF-state output current	$V_{CC} = 5.5 V$							
		$V_{O} = 2.7 V$		-	-	-	-	50	μΑ
		$V_{O} = 0.5 V$		-	-	-	-	-50	μΑ
lo	output current	$V_{CC} = 5.5 V$	[2]	-	-	-	-100	-225	mA
I _{CC}	supply current	V_{CC} = 5.5 V; V_{I} = GND or V_{CC}							
		outputs HIGH-state		-	50	-	-	70	mA
		outputs LOW-state		-	70	-	-	100	mA
		outputs OFF-state		-	60	-	-	90	mA

[1] All typical values are measured at V_{CC} = 5 V.

[2] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

10. Dynamic characteristics

Table 7.Dynamic characteristics

GND =	0	V∙ fr	or test	circuit	500	Figure	7
GND =	υ	v, 10	1 1031	uncun,	366	Iguie	/ .

Symbol	Parameter	Conditions	25 °C; V _{CC} = 5.0		25 °C; V _{CC} = 5.0 V 0 °C to 70 °C; V _{CC} = 5.0 V \pm 0.5 V		70 °C; V ± 0.5 V	Unit
			Min	Тур	Мах	Min	Max	
t _{PLH}	LOW to HIGH	An to Yn; see Figure 5						
	propagation delay	C _L = 50 pF	2.0	5.5	8.5	2.0	9.0	ns
		$C_L = 300 \text{ pF}$, 1 output switching	-	9.5	13.0	-	14.0	ns
		$C_L = 300 \text{ pF}$, 10 outputs switching	-	12.0	16.0	-	17.0	ns

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Symbol	Parameter	Conditions		25 °C; V _{CC} = 5.0 V		0 °C to 70 °C; V _{CC} = 5.0 V ± 0.5 V		Unit
				Тур	Max	Min	Max	
t _{PHL}	HIGH to LOW	An to Yn; see <u>Figure 5</u>						
	propagation delay	C _L = 50 pF	2.0	4.5	8.5	2.0	9.0	ns
		$C_L = 300 \text{ pF}$, 1 output switching	-	7.5	10.0	-	11.0	ns
		C_L = 300 pF, 10 outputs switching	-	14.0	17.0	-	18.0	ns
t _{PZH}	OFF-state to HIGH	OEn to Yn; see Figure 6						
	propagation delay	C _L = 50 pF	5.0	8.0	12.0	4.5	14.0	ns
		$C_L = 300 \text{ pF}$, 1 output switching	-	15.0	20.0	-	21.0	ns
		C_L = 300 pF, 10 outputs switching	-	15.0	20.0	-	21.0	ns
t _{PZL}	OFF-state to LOW	OEn to Yn; see Figure 6						
	propagation delay	C _L = 50 pF	4.0	6.0	10.5	4.0	11.5	ns
		$C_L = 300 \text{ pF}$, 1 output switching	-	9.5	13.0	-	14.0	ns
		C_L = 300 pF, 10 outputs switching	-	17.0	21.0	-	21.5	ns
t _{PHZ}	HIGH to OFF-state	OEn to Yn; see Figure 6						
	propagation delay	C _L = 50 pF	2.5	5.0	8.0	2.0	8.5	ns
		$C_L = 300 \text{ pF}$, 1 output switching	-	15.0	19.0	-	20.0	ns
		C_L = 300 pF, 10 outputs switching	-	15.0	19.0	-	20.0	ns
t _{PLZ}	LOW to OFF-state	OEn to Yn; see Figure 6						
	propagation delay	C _L = 50 pF	2.5	5.0	8.0	2.0	8.5	ns
		C_L = 300 pF, 1 output switching	-	9.5	13.5	-	14.0	ns
		$C_{L} = 300 \text{ pF}$, 10 outputs switching	-	12.5	15.5	-	16.0	ns

Table 7. Dynamic characteristics ...continued

GND = 0 V; for test circuit, see <u>Figure 7</u>.

11. Waveforms



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Table 8. Test data

Input			Load		V _{EXT}			
VI	fı	tw	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
3.0 V	1 MHz	500 ns	≤ 2.5 ns	50 pF	500 Ω	open	open	7.0 V

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12. Package outline



Fig 8. Package outline SOT137-1 (SO24)

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Fig 9. Package outline SOT340-1 (SSOP24)

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13. Abbreviations

Table 9.	Abbreviations
Acronym	Description
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 10.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74F827_4	20100129	Product data sheet	-	74F827_3				
Modifications: • The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.								
	 Legal texts have been adapted to the new company name where appropriate. 							
	 DIP 24 (SOT2 <u>12 "Package of</u> 	DIP 24 (SOT222-1) package removed from <u>Section 3 "Ordering information"</u> and <u>Section</u> 12 "Package outline"						
74F827_3	20040121	Product specification	-	74F827_74F828_2				
74F827_74F828_2	19941205	Product specification	-	-				

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15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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